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Lithography-free IR polarization converters via orthogonal in-plane phonons in α -MoO₃ flakes

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Exploiting polaritons in natural vdW materials has been successful in achieving extreme light confinement and low-loss optical devices and enabling simplified device integration. Recently, $\alpha\text{-MoO}_3$ has been reported as a semiconducting biaxial vdW material capable of sustaining naturally orthogonal in-plane phonon polariton modes in IR. In this study, we investigate the polarization-dependent optical characteristics of cavities formed using $\alpha\text{-MoO}_3$ to extend the degrees of freedom in the design of IR photonic components exploiting the in-plane anisotropy of this material. Polarization-dependent absorption over 80% in a multilayer Fabry-Perot structure with $\alpha\text{-MoO}_3$ is reported without the need for nanoscale fabrication on the $\alpha\text{-MoO}_3$. We observe coupling between the $\alpha\text{-MoO}_3$ optical phonons and the Fabry-Perot cavity resonances. Using cross-polarized reflectance spectroscopy we show that the strong birefringence results in 15% of the total power converted into the orthogonal polarization with respect to incident wave. These findings can open new avenues in the quest for polarization filters and low-loss, integrated planar IR photonics and in dictating polarization control.

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irefringence has revolutionized optical systems and has been tailored to many polarization-sensitive applications such as liquid-crystal displays¹, light modulators², spectroscopy systems³, waveplates⁴⁻⁶, nonlinear optical devices⁶⁻⁸ and biological tissue imaging⁹. Mid-infrared wavelength range encompasses an atmospheric window between 3 to 5 and 8 to 14 µm that is critical for remote sensing applications that require optical components. However, realizing these components in infrared (IR) remains challenging due to the scarcity of material systems that exhibit strong birefringence in this frequency range. Hyperbolicity ^{10,11} is an extreme form of birefringence where one or more of the crystal axes have a negative dielectric function, whilst the others are positive. Therefore, not only does hyperbolicity address anisotropy, but also, it reduces the required device dimensions by few orders of magnitude^{8,12}. Hyperbolicity is also the backbone of exceptional optical phenomena such as hyperlensing¹³⁻¹⁵, enhanced thermal radiation^{16,17}, canalization¹¹, and negative refraction¹⁸. Originally hyperbolicity was primarily demonstrated using artificial materials (aka metamaterials) consisting of reflective and transparent domains or dielectrics developed with intricate fabrication methods that rely on periodic sub-wavelength features patterned using laborious lithography techniques 12,19-22. As a result, the geometric quality of the periodic cell and associated fabrication non-idealities, compromises the photonic figures of merit of the devices²³. Natural hyperbolicity, on the other hand, has been reported in several materials that offer the advantage of relaxing expensive and timeconsuming micro/nanofabrication efforts^{12,24}. Thus, natural inplane hyperbolicity offers new possibilities for birefringent optical components and polarization-dependent photonics.

The emergence of van der Waals (vdW) materials and associated ease of integration with on-chip photonics has redirected interest to developing optical components based on them²⁵. These materials can be exfoliated down to monolaver thicknesses and transferred onto arbitrary substrates and incorporated into 2D heterostructures²⁶. Naturally hyperbolic vdW materials for IR are often studied in the context of polaritons, i.e., hybrid light-matter quasiparticles²⁷. Hexagonal boron nitride (hBN) is the most widely investigated of this class, featuring two Reststrahlen (RS) bands where hyperbolic phonon polaritons (PhP) can be supported^{28,29}. This results from the fact that within these two spectral bands, hBN exhibits negative values of the real part of the permittivity along either the in-plane or out-of-plane directions, while the orthogonal direction(s) exhibit positive values. In-plane anisotropy can be achieved within hBN via fabrication which provides opportunities for applications in polarization manipulation³⁰. However, in-plane hyperbolicity is not naturally supported in hBN due to the in-plane symmetry of its crystal lattice. In the context of hyperbolic plasmon polaritons (PPs), graphene and black phosphorus (BP) are the most widely studied materials. While graphene does not support in-plane anisotropy, simulation efforts have demonstrated that introducing anisotropy through asymmetric patterning achieves in-plane birefringence³¹. On the other hand, BP supports weak in-plane anisotropy and hence birefringence^{32,33}. In order to enhance anisotropy, BP can be patterned to support anisotropic plasmons which are shown to modify the polarization of the reflected or transmitted beam at IR frequencies^{34,35}. However, adding a substrate significantly deteriorates the amount of polarization rotation, as well as the intensity of the output, especially for the reflected beam³³. In order to boost the in-plane anisotropy and ameliorate the effect of the substrate, BP was considered in the free-standing form, rendering such devices impractical. Besides, in case of patterned vdW materials, due to the fast scattering times associated with lightelectron coupling, (Ohmic) losses are inherently high for PPs compared to PhPs¹⁰. Recent works demonstrated that in-plane hyperbolicity is naturally present in the highly anisotropic vdW 2D material α-MoO₃, featuring three distinct RS bands, resulting in a variety of different hyperbolic behaviors in the long-wave IR 36,37 . The low-loss PhPs supported by MoO $_3$ offer a platform to better control polarization in this spectral range. Here, we experimentally show that the naturally in-plane hyperbolicity of α -MoO $_3$ supports polarization-dependent resonant absorption (polarization filter) by optical phonons (OPh) and polarization conversion in the midinfrared when integrated into a FP cavity. Unlike PhPs that require momentum-matching techniques, OPhs require low momenta and can be directly excited with photons. As a result, the necessity of patterning with lithography techniques is obviated.

α-MoO₃ has garnered much attention as a biaxial vdW material, due to its polar and highly anisotropic optical phonons within the mid-infrared (MIR) that offers extra RS bands compared to hBN^{36,37}. In light of this discovery, a few publications have experimentally mapped the dispersion relation of flakes using near-field and far-field optical microscopies via scattering-type scanning near-field optical microscopy (s-SNOM) and Fourier transform infrared (FTIR) spectroscopy, respectively $^{36-40}$. The strong anisotropy in α -MoO₃, originating from lattice anisotropy, gives rise to three distinct lattice modes along the three orthogonal principle crystal directions leading to the previously reported naturally occurring in-plane hyperbolicity. α-MoO₃ is an orthorhombic crystal featuring three different symmetries for oxygen atoms that give rise to the biaxial optical properties (Fig. 1a)^{36,38}. As is the case for all polar crystals, these RS bands are bracketed by longitudinal (LO) and transverse (TO) optic phonons in each direction. The complex permittivity of α-MoO₃ is illustrated in Fig. 1b, c, which outline the three successive RS bands in directions identified in Fig. 1a as x, y, and z (see model below). Since α -MoO₃ can be exfoliated along the [010] crystal direction, this is dubbed the z direction (optical axis). Following the established convention of crystallographic directions in the literature, the x and y directions represent the [100] and [001] directions, respectively³⁶. The strong anisotropy of α-MoO₃ could be impactful for a wealth of applications, ranging from IR waveplates, polarization sensors, in-plane imaging and hyperlenses to in-plane chemical sensing³⁹. As a semiconductor, it can also enable a number of active nanophotonic concepts, while realizing heterostructures with other 2D vdW materials could pave the way to more versatile novel hybrid polaritons⁴¹.

In this study, we have carried out experiments that highlight some of the routes that can be investigated in more depth toward realizing large number of degrees of freedom and in-plane nanophotonics. Here, we use the polarization-dependent OPh modes of $\alpha\text{-MoO}_3$ to create a Fabry-Perot (FP) perfect absorber geometry, as illustrated in Fig. 1d. As an introduction, first, we model the dielectric function tensor of $\alpha\text{-MoO}_3$ to be used for transfer matrix method (TMM) and FDTD simulations 40 . We observe coupling of the FP and OPh modes in this system in simulations and experiments, indicative of strong coupling. The in-plane anisotropy of $\alpha\text{-MoO}_3$ has critical implications for planar, on-chip photonics and we demonstrate polarization filters (absorbers) and enhanced polarization conversion resulting from the multiple spectrally overlapping RS bands with simple, proof-of-concept experiments and supporting simulations.

Results

Optical model of \alpha-MoO₃. Since OPhs dominate the optical characteristics of α -MoO₃ in the mid-infrared, the complex permittivity can be described by phenomenological Lorentz function

$$\varepsilon = \sum_{j=x,y,z} \varepsilon_j \cdot \hat{j}, \ \varepsilon_j = \varepsilon_{\infty,j} \left(\frac{\omega_{\text{LO},j}^2 - \omega^2 - i\omega\Gamma_j}{\omega_{\text{TO},j}^2 - \omega^2 - i\omega\Gamma_j} \right) \tag{1}$$

where $\varepsilon_{\infty,j}$ and Γ_{j} , respectively, stand for the high frequency permittivity and phonon damping (broadening factor of Lorentz

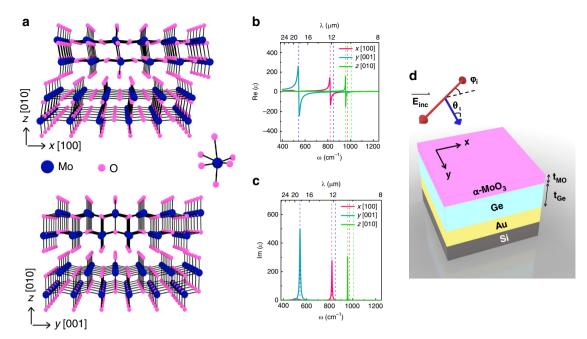


Fig. 1 Optical characteristics of α -MoO₃ and the structure under study. a Schematic representation of atomic orientation in the bulk structure of α -MoO₃ in xz and yz planes, (b) real and (c) imaginary parts of the dielectric function for α -MoO₃. d Schematic illustration of the investigated multilayer structure.

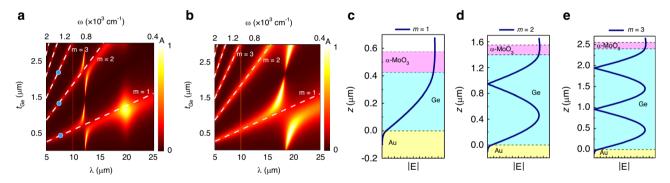


Fig. 2 Dispersion of α -MoO₃ FP cavity with $t_{\rm Ge}$. a Simulated dependence of total absorption on wavelength/frequency and Ge thickness ($t_{\rm Ge}$) where α -MoO₃ thickness is kept constant at $t_{\rm MO}=0.15\,\mu{\rm m}$ for (a) x ($\phi_i=0^{\circ}$) and (b) y ($\phi_i=90^{\circ}$) phonons. Simulated electric field magnitude |**E**| in the cross section of the studied multilayer system for $t_{\rm MO}=0.15\,\mu{\rm m}$ and (c) $t_{\rm Ge}=0.42\,\mu{\rm m}$ (m=1), (d) $t_{\rm Ge}=1.4\,\mu{\rm m}$ (m=2) and (e) $t_{\rm Ge}=2.4\,\mu{\rm m}$ (m=3). Note that the scales in panels **c**-**e** are not the same due to the $t_{\rm Ge}$ difference. The dashed lines in panels **a** and **b** represent the FP mode orders. The dots on panel **a** mark the mode profile simulations of panels **c**-**e**.

function), while $\omega_{\text{LO},j}$ and $\omega_{\text{TO},j}$ represent LO and TO phonon frequencies that bracket each RS band along the corresponding direction j. The values used for these parameters are taken from the recently reported experimental data by Álvarez-Pérez et al. 40 and the results are provided in Fig. 1b, c. It is evident from this figure that there are three RS bands between 540 and 1010 cm⁻¹ (9.9 and 18.5 µm), each of which is designated by vertical colorcoded dashed lines in Fig. 1b, c. As a result, there are various hyperbolic regions in this spectral range. For frequencies above $\omega = 1007 \, \mathrm{cm}^{-1}$ (wavelengths below $\lambda = 9.93 \, \mu \mathrm{m}$), the real part of permittivity along all directions is positive and unequal. At lower frequencies where 963 cm⁻¹ < ω < 1007 cm⁻¹, Re(ε_z) < 0 and Re $(\varepsilon_x) \operatorname{Re}(\varepsilon_z) > 0$ and $\operatorname{Re}(\varepsilon_y) > 0$, resulting in type 1 hyperbolicity in xz and yz planes, as shown in prior works 36,37,39,40 . At 547 cm $^{-1}$ $< \omega < 963 \, \mathrm{cm}^{-1}$ there are several bands of type 2 hyperbolicities, $\operatorname{Re}(\varepsilon_z) > 0$ and/or $\operatorname{Re}(\varepsilon_x)\operatorname{Re}(\varepsilon_z) < 0$, $\operatorname{Re}(\varepsilon_y)\operatorname{Re}(\varepsilon_z) < 0$. More importantly, when $545 \text{ cm}^{-1} < \omega < 821 \text{ cm}^{-1}$ we observe in-plane hyperbolicity that is essential for manipulating the polarization state of light impinging in the direction of optical axis (z).

Polarization-dependent absorption in α-MoO₃. As a simple geometry to exploit the polarization-dependent properties of α-MoO₃, we consider a FP structure consisting of an α-MoO₃ flake, a Ge cavity, and a gold back plane, illustrated in Fig. 1d. Ge is chosen to form the cavity due to its infrared transparency and lack of significant optical dispersion or loss within the frequency range of interest⁴². The absorption in the structure (equivalent to that of α-MoO₃, A_{MO}) is simply $A = A_{\text{MO}} = 1 - R$ where A and R represent absorbance and reflectance, respectively. The polarization of the impinging radiation (ϕ_i) is defined with respect to the x-axis throughout this study. The impact of the Ge thicknesses (t_{Ge}) on the spectral absorption of the FP structure under p-polarized incident light is illustrated in the simulation results presented in Fig. 2.

In an effort to gain the requisite insight into the spectral dependence of the cavity absorption on the Ge layer thickness, t_{Ge} , we simulated the structure using the TMM method (identical FDTD results with Lumerical in Supplementary Note 1). The results for x- optical phonons (OPh $_x$) and y-direction optical

phonons (OPh_v) are, respectively, provided in Fig. 2a, b. It can be inferred from these two panels that as t_{Ge} increases, the absorption ascribed to FP modes (white dashed lines) redshifts up to a certain thickness, they overlap with OPh_x (OPh_y) and an anti-crossing between the OPh and FP modes occurs. There are several higher-order FP modes that are marked by dashed lines that show similar behavior as that of the fundamental FP mode (m=1). In Fig. 2a, b oblique lines with steeper slopes represent higher-order FP cavity modes (more details in Supplementary Note 1). In order to verify the FP modes, electric field magnitude (|E|) simulations are provided in Fig. 2c-e. A hypothetical vertical line at $\omega = 1300 \, \text{cm}^{-1}$ ($\lambda \approx 8 \, \mu\text{m}$) in Fig. 2a or b would pass through 3 different modes marked on Fig. 2a with blue dots. These dots represent m = 1, 2, and 3 FP modes, respectively, at three different t_{Ge} values, $t_{Ge} = 0.42$, 1.4, and 2.4 µm. The simulated $|\mathbf{E}|$ for the mentioned t_{Ge} values in the cross-section of the multilayer structure is illustrated in Fig. 2c-e that verify the mode number engraved in the number of nodes within Ge laver. The electric field is similar for xz and yz cross sections. Also evident from Fig. 2a, b are the x and y phonons, respectively, at 820 cm^{-1} (12.2 µm) and 550 cm^{-1} (18.2 µm), as well as their forbidden-crossing with the discussed cavity modes. The vertical absorption lines observed in the vicinity of 10 µm $(\omega = 1000 \text{ cm}^{-1})$ in Fig. 2a, b represent the OPh_z modes, which can be stimulated with off-normal excitation. For the purpose of our simulations this was achieved by setting the incident angle (θ) to 25°. This value of the incident angle is defined by the weighted average incident angle of the Cassegrain objectives used for FTIR measurements and OPhz resonances are threfore expected to be excited in our experiments. Unlike OPh_x and OPh_y, OPh_z modes are orthogonal to the FP modes and thus they can be supported at the same frequency without strong modal interactions (e.g., anticrossing behavior).

In order to observe the traces of OPh modes and distinguish them from the FP cavity modes in reflection (or absorption) results, two values of $t_{\rm Ge}$, 0.42 and 0.85 µm, are identified from simulation results of Fig. 2a. For $t_{\rm Ge}=0.42$ µm, absorption based on OPh modes is expected as opposed to $t_{\rm Ge}=0.85$ µm, where coupling of OPh modes to the FP mode m=1 is anticipated (consider two horizontal line cuts from Fig. 2a at the mentioned $t_{\rm Ge}$ values). At these two values of $t_{\rm Ge}$, we also simulate the spectral characteristics of absorption in α -MoO₃ as a function of $t_{\rm MO}$ in Fig. 3a, b when $\phi_i=0^\circ$. An important take-away from Fig. 3a, b simulations is the increased number of supported OPh modes in α -MoO₃ for larger $t_{\rm MO}$ values³. As $t_{\rm MO}$ increases in

Fig. 3a, higher-order modes of OPhs also become accessible. At ω > 1000 cm⁻¹ (λ < 10 µm) since α -MoO₃ is highly dispersive, linear dependence of spectral absorption on t_{MO} is not expected. The oblique lines in this frequency range are FP-like (similar to Fig. 2a, b) which are a result of cavity formed by air-MoO₃-Ge layers. As t_{MO} increases, these lines become increasingly nonlinear as they approach the RS bands. This is expected since the onset of RS bands is concomitant to substantial changes in the dielectric function, namely the vicinity of $\omega_{LO,z}$, $\omega_{LO,x}$, and $\omega_{LO,y}$. When $800 \text{ cm}^{-1} < \omega < 1000 \text{ cm}^{-1}$ FP modes in α -MoO₃ cannot be supported in xz cross-section since the real part of the permittivity is negative in this range. Contrarily, for $\omega < 800 \text{ cm}^{-1}$, FP mode formed by air-MoO₃-Ge overlaps with m = 1 OPh_x mode and the hybrid mode redshifts and higher-order OPh_x appears at 820 cm⁻¹. The hybrid mode with fundamental OPh_x and higher order OPh_x mode are marked with purple dots in Fig. 3a and their corresponding |E| profiles are illustrated in Fig. 3c, d. In these figures, field profiles for the m=1 and m=2 when $t_{\rm MO}=0.95\,\mu{\rm m}$ and $t_{\rm Ge} = 0.42 \,\mu{\rm m}$ at $\omega = 660 \,{\rm cm}^{-1} \,(\lambda \approx 15 \,\mu{\rm m})$ and $\omega = 805 \,{\rm cm}^{-1}$ $(\lambda \approx 10 \,\mu\text{m})$ are presented in Fig. 3c, d, respectively, that support the presented mode discussion. Contrarily, in Fig. 3b where $t_{\rm Ge} = 0.85 \,\mu{\rm m}$, Ge is thick enough to support FP modes formed by MoO₃-Ge-Au layers at ω < 820 cm⁻¹ (λ > 12 μ m). Consequently, the m = 1 FP mode of Ge also interacts with the prior overlapping modes, m = 1 OPh_x and m = 1 FP of α -MoO₃. As a result of the three interacting modes (instead of two in the case of Fig. 3a), an additional extinction peak appears near ω < 900 cm⁻¹ which shows opposite trend to that of redshifting hybridized m=1 OPh_x and m = 1 FP of α -MoO₃. The splitting observed around 18 μ m is due to the OPhx mode near this wavelength. At xz cross-section, since α-MoO₃ is highly dispersive and has negative real permittivity values at fequencies between $\omega_{\text{LO},z}$ and $\omega_{\text{TO},x}$, the FP mode of α -MoO₃ is not present in this range. Contrarily, at $\omega < \omega_{TO,x}$ for xz cross-section ($\phi_i = 0^\circ$), α -MoO₃ has positive real permittivity values and its corresponding FP mode is feasible and it hybridizes with OPh_x modes. For yz cross-section ($\phi_i = 90^\circ$), similar behavior is expected except that the FP mode for α -MoO₃ is supported at ω < $\omega_{TO,\nu}$ (Supplementary Note 1).

In order to verify our predictions of the coupled FP-OPh modes in $\alpha\text{-MoO}_3$ experimentally, three samples like the one schematically illustrated in Fig. 1d were fabricated; sample S1 with $t_{\rm Ge}=0.42\,\mu\mathrm{m}$ and $t_{\rm MO}=0.15\,\mu\mathrm{m}$, sample S2 with $t_{\rm Ge}=0.42\,\mu\mathrm{m}$ and $t_{\rm MO}=0.95\,\mu\mathrm{m}$ and sample S3 with $t_{\rm Ge}=0.85\,\mu\mathrm{m}$ and $t_{\rm MO}=1.1\,\mu\mathrm{m}$. The spectral absorption measurements of these samples are presented in Fig. 4a–c, respectively. Details of the

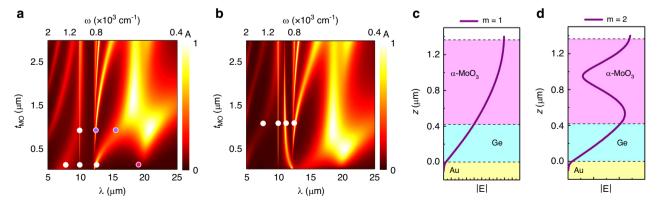


Fig. 3 Dispersion of α-MoO₃ FP cavity with t_{MO} . Simulated absorption versus wavelength/frequency and α-MoO₃ thickness (t_{MO}) in the multilayer structure for constant Ge thickness (t_{MO}) in the multilayer structure for constant Ge thickness (t_{MO}) in the multilayer structure for constant Ge thickness (t_{MO}) in the multilayer structure for constant Ge thickness (t_{MO}) in the cross section of the studied multilayer system for t_{MO} = 0.15 μm and t_{Ge} = 0.42 μm at (t_{MO}) t_{MO} = 660 cm⁻¹ (t_{MO}) and (t_{MO}) t_{MO} = 805 cm⁻¹ (t_{MO}). The dots in panels t_{MO} and t_{MO} and t_{MO} in the multilayer system for t_{MO} = 0.15 μm and t_{MO} = 0.42 μm at (t_{MO}) and t_{MO} = 805 cm⁻¹ (t_{MO}). The dots in panels t_{MO} and t_{MO} = 90° (supplementary Note 1).

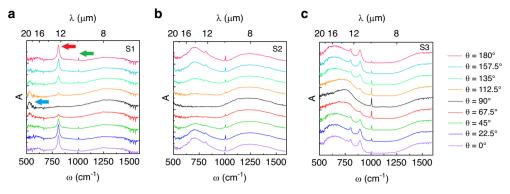


Fig. 4 Experimental polarization-dependent absorption spectra of α -MoO₃. Polarization-dependent absorption spectra of fabricated samples with different Ge and α -MoO₃ thickness ($t_{\rm Ge}$ and $t_{\rm MO}$, respectively), schematically illustrated in Fig. 1d with thick Au, (**a**) S1, $t_{\rm Ge}$ = 0.42 μm and $t_{\rm MO}$ = 0.15 μm, (**b**) S2, $t_{\rm Ge}$ = 0.42 μm and $t_{\rm MO}$ = 0.95 μm, and (**c**) S3, $t_{\rm Ge}$ = 0.85 μm and $t_{\rm MO}$ = 1.1 μm. Incident polarization (ϕ_i) is varied (bottom to top) from 0° to 180° in 22.5° revolution and illumination angle θ = 25° from FTIR. The green, red and blue arrows in (**a**) emphasize, respectively the OPh_z, OPh_x, and OPh_y. The peaks observed in each sample are marked on Fig. 3a, b.

fabrication and measurement methods are based on previous reports²⁸ and are provided in the "Methods" section, as well as in Supplementary Note 2^{43,44}.

Our FTIR spectra show that sample S1 ($t_{\text{Ge}} = 0.42 \,\mu\text{m}$ and $t_{\rm MO} = 0.15 \,\mu{\rm m}$) supports polarization dependent absorption, as shown in Fig. 4a as a function of the incident polarizations between 0° to 180° in steps of 22.5°. In this figure, the peak at 800 cm⁻¹ (12.5 μ m) results from absorption from OPh_x in α -MoO₃, due to its presence at 0 and 180°. At $\phi_i = 90^\circ$, another peak in the vicinity of 550 cm⁻¹ becomes apparent, corresponding to OPh_y (Fig. 4a highlighted with blue arrow). The absorption peak at 1000 cm⁻¹ originates from OPh, excited as a result of the off-normal incident angle of the Cassegrain objective lens of FTIR. Finally, the broad peak located at a frequency higher than the z-LO phonons corresponds to the fundamental FP mode. The absorption tied to OPh_r reaches over 80% for $\phi_i = 0^{\circ}$ (Supplementary Note 2) and the corresponding full width at half maximum (FWHM) is 26 cm^{-1} (0.4 µm) centered at $\omega = 811 \, \mathrm{cm}^{-1}$. These results are consistent with values observed from the other two samples as shown in Fig. 4b, c. In Fig. 4b (sample S2 with $t_{Ge} = 0.42 \,\mu\text{m}$ and $t_{MO} = 0.95 \,\mu\text{m}$) we observe two peaks in the RS band near 750 cm⁻¹; the narrow one at 811 cm⁻¹ is the higher order mode of the OPh_x (m = 2) and the broader one is the hybridized m=1 OPh_x and m=1 FP of α - MoO_3 that redshifts and broadens as t_{MO} increases. These two mode values are marked on Fig. 3a (purple dots) and the corresponding field profiles outlining m = 1 and 2 are put forth in Fig. 3c, d. The strong polarization dependence of these peaks confirms that they cannot be attributed to the Ge cavity, which due to its isotropic, cubic crystal structure exhibits no polarization dependence. Finally, the thickness parameters for the sample S3 $(t_{\rm Ge} = 0.85 \,\mu{\rm m} \text{ and } t_{\rm MO} = 1.1 \,\mu{\rm m})$ is designed so that the fundamental cavity mode is red-shifted to longer wavelengths (lower frequency), to the vicinity of OPh_x modes. As a result, the m = 1 FP mode overlaps with m = 1 OPh_x and m = 1 α -MoO₃ FP modes and strong coupling is evident by the splitting that occurs in the absorption spectra of Fig. 4c. Thus, two distinct peaks at 811 and $720 \,\mathrm{cm}^{-1}$ are present for the three coupled modes compared to only two for sample S2, which is in line with our predictions of the modal overlap. Finally, the dots on simulation results of Fig. 3a, b mark the observed peaks in experimental results (Fig. 4a-c) and they agree well with simulations. The experimental results demonstrate strong polarization-dependent absorption; Fig. 4a represents 80% absorption and our simulations estimate 100% in the absence of experiment non-idealities. From a more general perspective, Fig. 4c indicates that one can

tune absorption to over 70% (100% in simulations) approximately at 900 and $820\,\mathrm{cm}^{-1}$ demonstrating dual-band polarization-dependent perfect absorption action. Due to the flake roughnesses and small flake dimensions compared to the wavelength of test, the experimental results exhibit lower absorption peaks than simulations. The results presented in this section are also evidences of strong birefringence observed by polarization-sensitive absorption and filtering action, particularly at $\omega_{\mathrm{TO},x}$. The polarization filtering contrast, defined as $\Delta R = R(\phi_I = 90) - R(\phi_I = 0)$, is $\Delta R \approx 70\%$ for Sample S1 at $811\,\mathrm{cm}^{-1}$. Benefitting modal overlap engineering by tuning the thickness of $\alpha\text{-MoO}_3$ and Ge layers, polarization filtering can be realized at several frequency values other than $\omega_{\mathrm{TO},x}$ particularly at 705 and 892 cm⁻¹ for samples S2 and S3, respectively. Theoretical values for filtering efficiency are above 90% for all of the absorption peaks.

A few discrepancies are evident in the experimental results compared to FDTD and TMM simulations. For all the samples (Fig. 4a-c), OPh_z resonances distinctly reside close to 1000 cm⁻¹ and show wide variations in intensity. We attribute this to the roughness of α-MoO₃ flakes (Supplementary Note 2) as well variations in the high frequency dielectric constant, which will result in some difference in intensity as the polarization state is rotated. The rough surface acts to diffract the radiation, which in turn gives rise to E components aligned along the optical axis (z)to excite OPh_z. In Fig. 4c, the OPh_z absorption peak at 1006 cm⁻¹ (9.94 µm) reaches to 53% and the FWHM and quality factor are 8.5 cm^{-1} (0.084 µm) and 119, respectively. The higher intensity of OPh_z peaks for samples S2 and S3 compared to S1 are due to the thicker α-MoO₃ flakes in these samples. Another major consequence of roughness is the suppression of OPh, in samples S2 and S3 in all samples. In order for this mode to be observed, a flake should have negligible roughness in comparison to 18 µm free-space wavelength of the OPh_v. The largest flake dimensions are on the order of 30 to 40 µm, which together with the surface roughness of the α-MoO₃ flakes studied, hinder the observation of clear, high quality OPh_v and lower frequency OPh_x signals (Supplementary Note 2).

Enhanced birefringence from in-plane RS bands. A crucial outcome of in-plane anisotropic OPhs is strong intrinsic birefringence. Whilst ω_{TO} frequencies were tailored to absorbers and polarization filters in the previous section, off-resonance frequencies ($\omega \neq \omega_{TO}$) where absorption drops, are suitable for waveplates and polarization conversion applications. The multiple RS bands of α-MoO₃ gives rise to unique polarization rotation capabilities for IR photonics. In order to demonstrate its

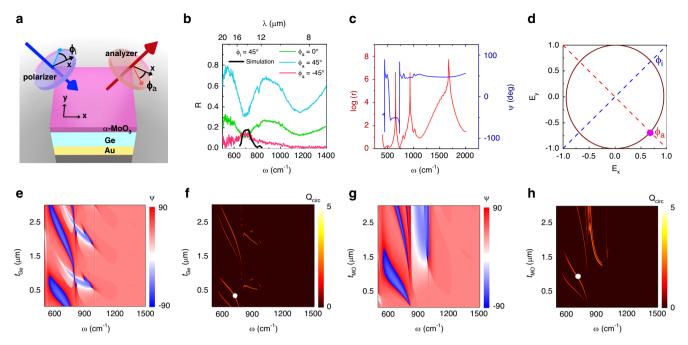


Fig. 5 RS band enhanced birefringence in α-MoO₃. a Schematic of depolarization experiment, (**b**) reflectance of sample S2 for different analyzer values ϕ_a when polarizer is set to $\phi_i = 45^\circ$, the black curve is the simulated intensity for $\phi_a = -45^\circ$. **c** Simulated polarization ellipse characteristics, ellipticity (r) and polarization ellipse major axis angle (ψ). **d** Simulated polarization ellipse of reflected beam at $\omega = 727$ cm⁻¹ which represents circularly polarized light. The purple dot represents an example of the |**E**| value from the reflected polarization ellipse at $\omega = 727$ cm⁻¹ used for obtaining the black simulation curve in panel **b**. **e** Spectral polarization ellipse major axis angle (ψ) versus Ge thickness ($t_{\rm Ge}$) and (**f**) spectral quarter-wave plate action quality factor ($t_{\rm Ge}$) versus $t_{\rm Ge}$, with $t_{\rm Ge}$ -MoO₃ thickness $t_{\rm MO}$ = 0.95 μm and incident angle $t_{\rm Ge}$ -25° and $t_{\rm Ge}$ -45°. **g** $t_{\rm Ge}$ -25° and $t_{\rm Ge}$ -25°. The white dots in panels **f** and **h** are the experiment data points representing the circularly polarized reflected beam in panel **d**.

potential, we have carried out a simple, proof-of-concept experiment as illustrated in Fig. 5a, on sample S2. In the FTIR experiment, one linear polarizer is placed on the path of incident beam (polarizer) and one in the path of the reflected beam, before the detector (analyzer). These linear polarization angles are defined with respect to x-axis and are represented with ϕ_i and ϕ_a , respectively, for polarizer and analyzer (Fig. 5a). The experimental reflectance results for $\phi_i = 45^\circ$ and different values of ϕ_a is provided in Fig. 5b.

Given the in-plane hyperbolicity of α -MoO₃ between x and yphonon resonances, we anticipate a different polarization state for the reflected beam. In Fig. 5b, when $\phi_i = \phi_a = 45^\circ$, we observe the reflectance pattern similar to Fig. 4b (R = 1 - A) except that the intensity is lower since a proportion of the power is lost as the reflected beam filters out any polarization other than ϕ_a . Keeping $\phi_i = 45^{\circ}$ and modifying to $\phi_a = 0^{\circ}$ results in decreased reflected intensity, which is expected, again due to filtering of the polarization. The most interesting scenario unfolds when analyzer is cross-polarized to have 90° phase difference with the incident beam ($\phi_i = 45^\circ$, $\phi_a = -45^\circ$). If the material were isotropic, the reflected cross-polarized signal would vanish, however, there is reflected intensity that peaks at 727 cm⁻¹ as high as 15% from this sample. This infers significant depolarization taking place in the sample and justifies significant polarization rotation associated with the in-plane anisotropy within the lowest frequency RS band. Whilst in principle the addition of a quarter wave plate would allow us to characterize the polarization state of this reflected beam, accurate quarter wave plates are not commercially available covering this spectral range. Therefore, we rely on FDTD simulations, replicating the experimental configuration, to shed light on the spectral depolarization characteristics of the reflected beam.

Sample S2 has been simulated using FDTD in identical experiment conditions to show that our cavity design supports a

range of different polarization states and polarization ellipse rotations, specifically, circularly polarized reflected light from a linearly polarized incident beam. The far-field polarization ellipse characteristics of the structure for reflected beam is extracted and fitted to the ellipse equation, $E_x/E_{0x}^2 + E_y/E_{0y}^2 - 2(E_xE_y/E_{0x}E_{0y})\cos(\delta) = \sin^2(\delta)$, where $\delta = \delta_y - \delta_x$ is the phase difference between the phases of electric field vectors in y and x directions and $2E_{0x}$ and $2E_{0y}$ are the major and minor axes of the polarization ellipse. Circularly polarized reflectance requires the phase difference between E_x and E_y (δ) to be 90° and their amplitude ratio to be 1 to satisfy a circle equation. Figure 5c illustrates the logarithmic scale of the ellipticity $(r = E_{0y}/E_{0x})$, i.e., the ratio of major to minor axes of the polarization ellipse (blue curve). In this plot, spikes represent linearly polarized light, where the logarithmic ratio is presented; otherwise, the spikes at linear polarization points would compromise the legibility of other data points. In particular, this logarithmic plot approaches zero at $\omega = 727 \text{ cm}^{-1}$, representing almost equal E_{0x} and E_{0y} amplitudes with exact ratio of r = 1.066. The red curve in Fig. 5c represents the angle of major axis of the polarization ellipse with respect to x axis (ψ) . The step near $\omega = 730 \, \text{cm}^{-1}$ for this curve has a significant implication; the polarization ellipse and hence field amplitudes extend for both axes, until near 727 cm⁻¹, the major axis is abruptly changed from values close to 45° to the ones near -45° . During this transition, there exists a frequency at which major and minor axes are equal in amplitude and the phase difference between E_x and E_y approaches 90°. This happens at 727 cm⁻¹ where $\delta_y - \delta_x = -89.16^{\circ}$. Thus, at $\omega = 727 \text{ cm}^{-1}$, $\alpha - \text{MoO}_3$ changes the linearly polarized incident light to a circularly polarized reflected beam, the polarization ellipse of which is illustrated in Fig. 5d, representing left-handed circularly polarized light. In order to draw a connection between simulation and experiment we record the spectral ratio of the total electric field in $\phi_a = -45^{\circ}$ direction (dashed red line in Fig. 5d) to the electric

field of the incident intensity ($\phi_i = 45^\circ$, blue dashed line in Fig. 5d) from the simulations. In other words, the magnitude of the normalized electric field ($|\mathbf{E}|$) is recorded in the intersection of reflected polarization ellipse with analyzer $\phi_a = -45^\circ$ at several frequency points (purple dot in Fig. 5d is an example at $\omega = 727 \, \mathrm{cm}^{-1}$). Afterwards, the normalized field value is squared to represent intensity and is multiplied to the spectral reflectance curve measured for sample S2 in Fig. 4b when $\phi_i = 45^\circ$ (R = 1 - A), where A is the dark green curve in Fig. 4b for $\phi_i = 45^\circ$). The result is the black curve in Fig. 5b which follows the peak trend of the experimental pink curve. Figure 5b shows that 15% of the incident beam is converted to cross-polarized state. Hence, linearly polarized incident light is modified to circularly polarized reflected light at $\omega = 727 \, \mathrm{cm}^{-1}$ from measurements, exhibiting quarter-wave plate action at IR frequencies.

Quarter-wave plate frequency can be tuned by adjusting the thickness of layers in this FP structure. With the aim of obtaining circularly polarized radiation in the reflected beam, the spectal polarization ellipse major axis angle (ψ) versus Ge thicness ($t_{\rm Ge}$) and α -MoO₃ thickness ($t_{\rm MO}$) are provided, respectively in Fig. 5e, g. The transformation of ψ between positive and negative values marks a transformation that can support quarter-wave plate action. The transitions lay between the blue and red regions in Fig. 5e, g. A quality factor can be defined to track the behavior of circular polarization as follows,

$$Q_{\text{circ}} = \ln\left(\left|\frac{1}{\frac{\pi}{2} - |\delta| + (1 - r)}\right|\right) \tag{2}$$

Equation (2) takes the two conditions of circularly polarized light into account; Qcirc becomes very large when the phase difference between E_y and E_x is 90° ($|\delta| = \pi/2$) and magnitude ratio of the two in-plane components of the fields is 1 (r=1). The logarithmic scale is used to improve the clarity of the resulting acceptable data points. In order to single out the most reliable conversions, δ and r are only allowed to deviate from the ideal circularly polarized case by an error margin of 5%. The results for sweeping t_{Ge} and t_{MO} are, respectively, demonstrated in Fig. 5f, h which are in agreement with the previously simulated results with FDTD full-wave software in Supplementary Figure 6c and d. As observed earlier, the lines in Fig. 5f, h are all located within the borders of the negative and positive ψ transformations in Fig. 5e, g. We also note that significant depolarization to states other than circular also takes place in this polarization conversion. The mentioned discrepancy is attributed to the rough surface of α-MoO₃ flakes, minimization of which is canonical for efficient polarization conversion applications. In the case of smooth α-MoO₃ flakes, using simulated reflectance curve from sample S2 for $\phi_i = 45^{\circ}$ instead of the experimental one, we predict conversion efficiency of over 90% as the ideal limit where all the non-ideal effects are absent. The observed reflectance in experiments, however, suggests a combination of different polarizations that obstructs high efficiency for single polarization in the output. Besides, other polarization rotation and states are also attainable by this configuration. As an example, the ellipticity demonstrates spikes (large r) which represent linearly polarized reflected beam. At $\omega = 655$ cm⁻¹, r = 736, and $\psi = -50.4$ ° which infers that for the reflected beam, linear polarization state of the incident beam is maintained and is rotated by -95.4° .

The flake thicknesses required for quarter and half-wave plate actions are more than an order of magnitude smaller than the wavelength of interest. OPhs render the refractive index of α -MoO₃ dispersive. The limit for thinner flakes for polarization conversion action can be pushed further if the frequency of operation is set closer to the OPh resonances. In such a scenario,

however, there exists a trade-off between thin flake and loss of power since OPhs absorb light. It is worth pointing out that for an α-MoO₃ layer on Ge substrate (i.e., absence of Au layer), the required α-MoO₃ thickness values are two times higher compared to the FP structure proposed in this study. In addition, due to the existence of transmittance in the absence of Au layer, it is more challenging to satisfy the amplitude condition of half-wave plate action which sets more limitations on the accessible frequency and thickness values for circularly polarized radiation. The reflected power in the absence of Au layer is at least 15% less which demonstrates the significance of FP structure for higher efficiency, thinner requirement for samples and the availability of more thickness parameters for tuning (t_{MO} and t_{Ge} in contrast to only $t_{\rm MO}$ for the structure in the absence of Au). The polarization characteristics can also be tuned with the incident polarization angle, which are provided in Supplementary Note 3 along with the results for α -MoO₃-Ge structure.

It is worth pointing out that in-plane anisotropic 2D materials have been previously investigated for birefringence and dichroism. Particularly, anisotropic plasmons observed in black phosphorus (BP) were examined to modify the polarization of the reflected or transmitted beam at IR frequencies. However, adding a substrate proved to be detrimental for efficiency and the relevant studies were restricted to simulations of patterned freestanding BP. Moreover, unlike α-MoO₃, BP is unstable in the ambient and needs to be capped with dielectrics which affect the efficiency. The highest reported reflected 90° polarization rotation reported in simulation studies are in the order of 10%33,34. Here, without any film patterning, we have a true experimental demonstration of 90° polarization rotation (Supplementary Note 3) in reflectance mode at IR frequencies which reaches to measured value of 12% reflectance in this study and is comparable to the theoretical reports with patterned anisotropic plasmonic materials, while we anticipate a theoretical value of 90% for ideal and smooth flakes. This experiment emphasizes the potential of α-MoO₃ for modifying the polarization of radiation in the IR obviating the need for patterning.

Discussion

In this work we have demonstrated the polarization-dependent optical responses of α-MoO₃ FP cavities numerically and experimentally. α-MoO₃ is a vdW semiconductor with strong longitudinal and transverse optical phonon resonances that give rise to high-quality absorption peaks in all the three orthogonal directions distinctly. In order to verify this, α-MoO₃ flakes were transferred to a multilayer cavity structure composed of Au and Ge. FDTD simulations and TMM method was used to analyze the structure and dispersion relations were obtained by scrutinizing the contribution of each layer to the absorption/reflection characteristics. The observed strong anisotropy in the simulations were confirmed experimentally that supported the existing strong birefringence. By engineering the layer thicknesses, on-resonance absorption peaks of over 80% were observed for OPh_x and quality factors as high as 119 were verified experimentally for OPhz. Afterwards, the off-resonance RS-band enhanced in-plane birefringence of α-MoO₃ was demonstrated experimentally with corroborating simulations that showed 15% reflectance to the cross-polarized state. This has implications for IR photonics as α-MoO₃ naturally enables modification of the amplitude, phase and polarization state of radiation essentially eliminating the need for patterning and further processing. It was also demonstrated that tailoring mode engineering through the tuning of the thickness of layers in FP configuration, polarization filtering and rotating frequency can be tuned for on-demand photonic applications.

Given the growing interest in PhPs as low-loss polaritons for photonic applications at IR wavelengths, α-MoO₃ is a valuable addition to the family of vdW materials. Despite having access to high-quality phonon resonances in hBN, there remain restrictions on IR photonics since hBN is uniaxial and an insulator. Furthermore, for all PhP-supporting materials, the frequency domain over which the RS band is realized is dictated by the optic phonon frequencies, with minimal tuning possible. However, integration of free-carrier injection for a semiconducting PhP material offers the potential to leverage the LO-phonon-plasmon-coupling (LOPC) effect to induce spectral tuning of the PhP modal frequencies⁴⁵. The semimetal graphene and semiconductor black phosphorus have been confirmed, respectively, as plasmonic and anisotropic plasmonic materials for IR photonics. The addition of vdW semiconducting α-MoO₃ with biaxial properties can relax several restrictions in photonic device design and combined with the existing wealth of IR vdW actively tunable plasmonic and phononic materials, paves the path to the next generation of switchable photonic integrated devices for the less investigated IR frequencies. We envisage that high-quality α-MoO₃ layers can achieve large-area and efficient polarization-sensitive optical components in IR as the fabrication techniques mature to provide large-area, smooth α-MoO₃ films.

Methods

Multilayer structure fabrication. The multilayer FP structure was fabricated using physical vapor deposition (PVD) techniques. Au was deposited using AJA eBeam Evaporator system and the base and deposition pressures were, respectively, 2×10^{-6} and 9×10^{-6} Torr. The deposition rate was 0.5 m/s. Ge was similarly deposited using Auto eBeam evaporation system with base and deposition pressure of 2×10^{-6} and 5×10^{-6} Torr. The deposition rate of this sublime material was held within 0.13 and 0.17 nm/s during the deposition.

α-MoO₃ **fabrication and transfer**. α-MoO₃ flakes were grown using low pressure PVD. For this process, 50 mg of MoO₃ (Sigma-Aldrich) powder was spread evenly within an alumina boat. This boat was placed within a 1-inch diameter quartz tube and at the center of a small Lindberg tube furnace. A 41 inch² rectangular piece of SiO₂/Si wafer (300 nm oxide thickness) was placed face-up downstream in a colder zone of the furnace. These pieces were suspended on top of an alumina boat and were located roughly 4 cm from the center region. The pressure was maintained at 2.8 Torr with a carrier gas of O₂ at a flow rate of 25 sccm. The center of the furnace was then heated to 675 °C over a period of 25 min and then to 700 °C over a period of 5 min upon reaching 700 °C, the furnace was immediately opened, thereby quenching the deposition.

A polycarbonate-based process was used to transfer the deposited flakes from the $\mathrm{SiO}_2/\mathrm{Si}$ substrate to several different substrates. This process involved coating the $\mathrm{SiO}_2/\mathrm{Si}$ substrate with a polycarbonate solution (5% polycarbonate to 95% chloroform by weight) at 2000 rpm for 60 s and baking at 120 °C for 1 min The substrate was then placed in water to allow the polycarbonate film and deposited α -MoO₃ flakes to naturally delaminate from the film. The polycarbonate film was then removed from the water and allowed to dry. Once dry, the polycarbonate film was placed onto the target substrate and baked at 170 °C for 15 min Finally, the target substrate was soaked overnight in chloroform and rinsed in isopropyl alcohol immediately thereafter to dissolve the polycarbonate film and leave only the α -MoO₃ flakes.

FTIR characterization. Mid-infrared reflectance measurements were taken with Hyperion 2000 IR microscope coupled to a Bruker Vertex 70 FTIR spectrum. For the FP structures MCT detector with KRS5 polarizer was used. The Cassegrain objective was 36× and the aperture dimensions were 50 by 50 μm^2 and the spectra were taken with 22.5° polarization steps. The polarizers used for the depolarization experiments were KRS5 wire grid polarizer from pike technologies and HDPE wire grid polarizer.

Data availability

The data that support the findings of this study are available from the corresponding author upon reasonable request.

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Author contributions

S.A.D., X.S., and K.A. conceived the idea, S.A.D. designed the devices and conducted the fabrication, experiments, measurements, and simulations and prepared the paper. T.G.F. designed the depolarization experiment, conducted low frequency FTIR experiments and helped in direction and writing of the paper. A.M. contributed in the growth, transfer, and characterization of $\alpha\text{-MoO}_3$ flakes. X.S. took part in design, measurements, and FP simulations. I.T. contributed in the simulations of depolarization. All authors commented on the manuscript and V.P.D., J.D.C., and K.A. supervised the project.

Competing interests

The authors declare no competing interests.

Additional information

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